## NSN 5961-01-363-1088

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-1088 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **End Application:** Milstar **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and electrostatic sensitive **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 420.0 reverse voltage, total rms **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Test Features:** Selected ant tested for the milstar Irip program **Test Data Document:** 49956-g494565 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:** 

No Fiig:

**Demilitarization:** 

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